

ZHM800-2500/50

MIL Grade High Power Amplifier

This is a high power, broadband, silicon carbide (SiC) RF amplifier that operates from 0.8 to 2.5 GHz. This PA is ideal for broadband military platforms as well as commercial applications. It is packaged in a modular housing that is approximately 8.0" by 8.0" by 1.5". This amplifier has a typical P3dB of 70 watts at room temperature. Noise figure at room temperature is 12.0 dB typical. Class AB current is ~6.3 amps typical employing a +50 Vdc supply.

- Solid-state Class AB linear design
- Compact, lightweight, rugged and reliable
- · Extremely wide instantaneous bandwidth
- Suitable for CW, AM, and FM (Contact factory for other modulation types)
- 50 ohm input/output impedance
- · Built-in control, monitoring and protection circuits



Electrical Specifications							
PARAMETER	SYMBOL	MIN.	TYP.	MAX	UNITS		
Operating Frequency	BW	800		2500	MHz		
Output Power CW	P _{SAT}	50			Watt		
Small Signal Gain	G _{SS}	46	48		dB		
Input Power for Rated P _{SAT}	P _{IN}		0		dBm		
Switching Speed (10% to 90%)	T _{ON/OFF}		2.0		us		
Small Signal Gain Flatness	ΔG_{SS}			±2.0	dB		
Third Order Intercept Point 2-Tones, 34dBm/Tone., 1.0MHz Spacing	IP3	+50			dBm		
Input Return Loss	S ₁₁			-10	dB		
Noise Figure @ Max Gain	NF			10	dB		
Harmonics @ P _{OUT} = 20W	2 ND / 3 RD			-17/20	dBc		
Spurious Signals	Spur			60	dBc		
Operating Voltage	Vdc	26	28	30	Volt		
Quiescent Current	Ι _{DQ}		2.0		Amp		
Output Power @ 1dB Gain Compression	P _{1dB}		20		Watt		
Current consumption @ P _{OUT} = 50W	I _{DD}			6.0	Amp		



ZHM800-2500/50

MIL Grade High Power Amplifier

Mechanical Specifications						
PARAMETER	VALUE	UNITS	LIMITS			
Dimensions	3.5" X 7.5" X 1.0"	Inch	Max			
Weight	1.0	lb	Max			
RF Connectors In/Out	SMA Female					
DC Connectors						
Cooling	External Heatsink (Not Supplied)					